MC14001B Series

B-Suffix Series CMOS Gates

MC14001B, MC14011B, MC14023B, MC14025B, MC14071B, MC14073B, MC14081B, MC14082B

The B Series logic gates are constructed with P and N channel enhancement mode devices in a single monolithic structure (Complementary MOS). Their primary use is where low power dissipation and/or high noise immunity is desired.

Features

- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- All Outputs Buffered
- Capable of Driving Two Low−power TTL Loads or One Low−power Schottky TTL Load Over the Rated Temperature Range.
- Double Diode Protection on All Inputs Except: Triple Diode Protection on MC14011B and MC14081B
- Pin−for−Pin Replacements for Corresponding CD4000 Series B Suffix Devices
- Pb−Free Packages are Available*

MAXIMUM RATINGS (Voltages Referenced to V_{SS})

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage Range	−0.5 to +18.0	V
V_{in}, V_{out}	Input or Output Voltage Range (DC or Transient)	−0.5 to V_{DD} + 0.5	V
I_{in}, I_{out}	Input or Output Current (DC or Transient) per Pin	±10	mA
P_D	Power Dissipation, per Package (Note 1)	500	mW
T_A	Ambient Temperature Range	−55 to +125	°C
T_{stg}	Storage Temperature Range	−65 to +150	°C
T_L	Lead Temperature (8−Second Soldering)	260	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Temperature Derating:
   Plastic “P and D/DW” Packages: – 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high−impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \le (V_{in}$ or $V_{out}) \le V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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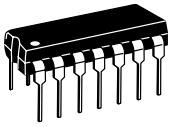
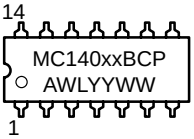
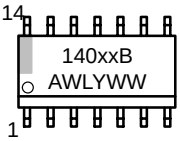
MARKING DIAGRAMS



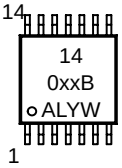
PDIP−14
P SUFFIX
CASE 646

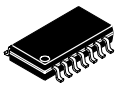


SOIC−14
D SUFFIX
CASE 751A

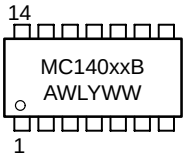


TSSOP−14
DT SUFFIX
CASE 948G





SOEIAJ−14
F SUFFIX
CASE 965



xx = Specific Device Code
A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week

DEVICE INFORMATION

Device	Description
MC14001B	Quad 2−Input NOR Gate
MC14011B	Quad 2−Input NAND Gate
MC14023B	Triple 3−Input NAND Gate
MC14025B	Triple 3−Input NOR Gate
MC14071B	Quad 2−Input OR Gate
MC14073B	Triple 3−Input AND Gate
MC14081B	Quad 2−Input AND Gate
MC14082B	Dual 4−Input AND Gate

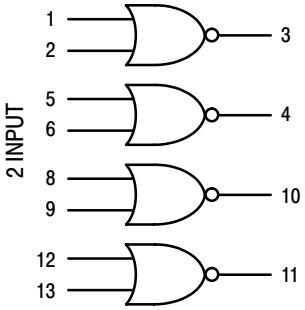
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

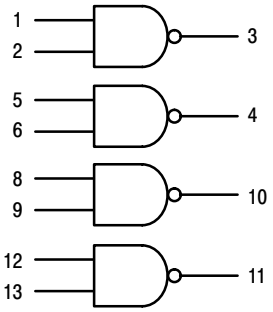
LOGIC DIAGRAMS

NOR | NAND | OR | AND

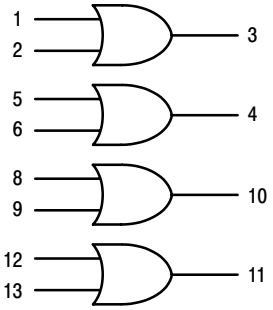
MC14001B
Quad 2−Input NOR Gate



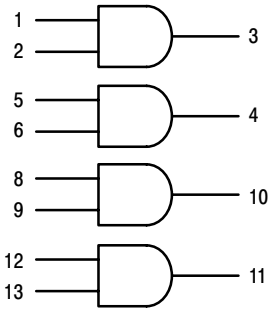
MC14011B
Quad 2−Input NAND Gate



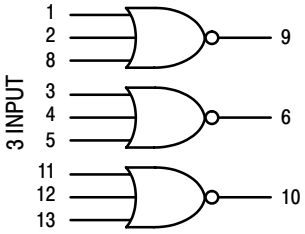
MC14071B
Quad 2−Input OR Gate



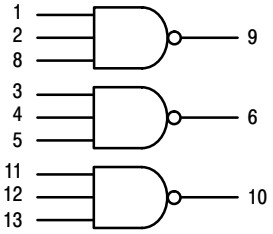
MC14081B
Quad 2−Input AND Gate



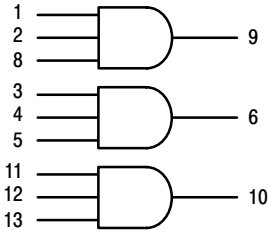
MC14025B
Triple 3−Input NOR Gate



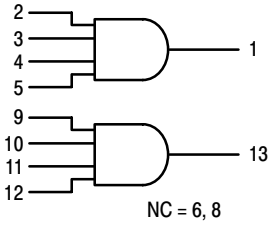
MC14023B
Triple 3−Input NAND Gate



MC14073B
Triple 3−Input AND Gate



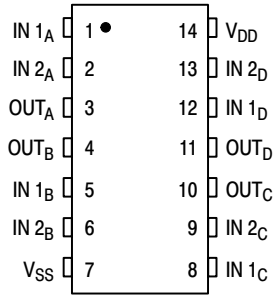
MC14082B
Dual 4−Input AND Gate



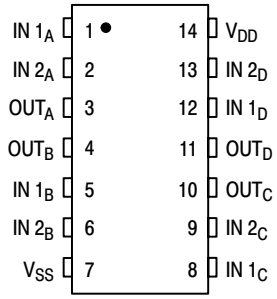
V_{DD} = PIN 14
V_{SS} = PIN 7
FOR ALL DEVICES

PIN ASSIGNMENTS

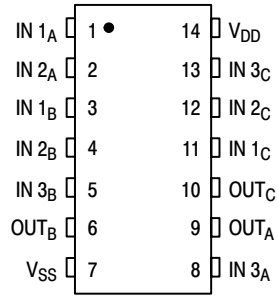
MC14001B
Quad 2−Input NOR Gate



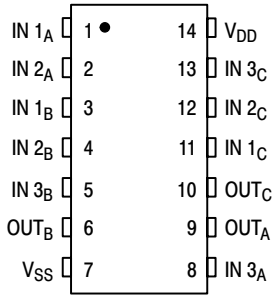
MC14011B
Quad 2−Input NAND Gate



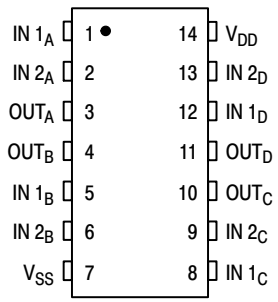
MC14023B
Triple 3−Input NAND Gate



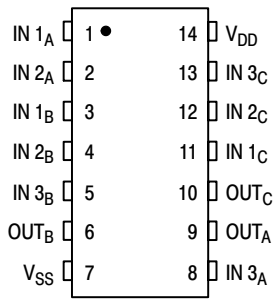
MC14025B
Triple 3−Input NOR Gate



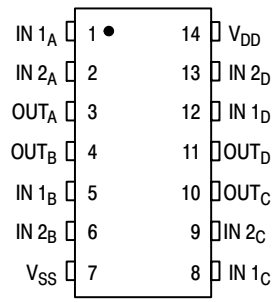
MC14071B
Quad 2−Input OR Gate



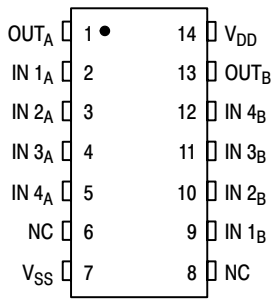
MC14073B
Triple 3−Input AND Gate



MC14081B
Quad 2−Input AND Gate



MC14082B
Dual 4−Input AND Gate



NC = NO CONNECTION